

**TO THE INTERNATIONAL BUREAU OF WIPO**

In re Application of:  
**Intel Corporation**

Application No.: PCT/US2017/054566

Filed: September 29, 2017

For: GROUP III-NITRIDE (III-N) DEVICES WITH  
REDUCED CONTACT RESISTANCE AND  
THEIR METHODS OF FABRICATION

Docket No.:  
01.P120301PCT

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The International Bureau of WIPO  
Attention: PCT Services Dept.  
34 chemin des Colombettes  
1211 Geneva 20  
Switzerland

REQUEST TO RECORD A CHANGE UNDER RULE 92bis

Dear Sir or Madam:

Pursuant to Rule 92bis, please find attached a replacement Page 1 of RO101, correcting Inventor address's in the above referenced application:

**INVENTOR ONLY:**  
**All designated States**  
**RADOSAVLJEVIC, Marko**  
**3684 NW Loriann**  
**Portland, Oregon 97229**  
**United States of America**

It is respectfully requested that a PCT/IB/306 form setting forth the correction of Inventor address be issued.

Please direct any inquiry concerning this matter to the Agent, James M. Howard at 503-968-8233.

Respectfully submitted,  
**GREEN, HOWARD, & MUGHAL, LLP**

October 20, 2017

Date

/James M. Howard/

James M. Howard

Reg. No. 56,377

Attorney for Applicants

5 Centerpointe Drive, Suite 400  
Lake Oswego, OR 97035  
(503) 968-8233  
[docketing@ghmip.com](mailto:docketing@ghmip.com)

**PCT REQUEST**Original (for **SUBMISSION** )

<b>0</b>	<b>For receiving Office use only</b>	
<b>0-1</b>	International Application No.	
<b>0-2</b>	International Filing Date	
<b>0-3</b>	Name of receiving Office and "PCT International Application"	
<b>0-4</b>	<b>Form PCT/RO/101 PCT Request</b>	
0-4-1	Prepared Using	<b>PCT-SAFE [EFS-Web mode] Version 3.51.078.254 MT/FOP 20170701/0.20.5.24</b>
<b>0-5</b>	<b>Petition</b> The undersigned requests that the present international application be processed according to the Patent Cooperation Treaty	
<b>0-6</b>	<b>Receiving Office (specified by the applicant)</b>	<b>United States Patent and Trademark Office (USPTO) (RO/US)</b>
<b>0-7</b>	<b>Applicant's or agent's file reference</b>	<b>01P120301PCT</b>
<b>I</b>	<b>Title of Invention</b>	<b>GROUP III-NITRIDE (III-N) DEVICES WITH REDUCED CONTACT RESISTANCE AND THEIR METHODS OF FABRICATION</b>
<b>II</b>	<b>Applicant</b>	
II-1	This person is	<b>Applicant only</b>
II-2	Applicant for	<b>All designated States</b>
II-4	Name	<b>INTEL CORPORATION</b>
II-5	Address	<b>2200 Mission College Blvd Santa Clara, California 95054 United States of America</b>
II-6	State of nationality	<b>US</b>
II-7	State of residence	<b>US</b>
<b>III-1</b>	<b>Applicant and/or inventor</b>	
III-1-1	This person is	<b>Inventor only</b>
III-1-3	Inventor for	<b>All designated States</b>
III-1-4	Name (LAST, First)	<b>RADOSAVLJEVIC, Marko</b>
III-1-5	Address	<b>3684 NW Loriann Portland, Oregon 97229 United States of America</b>